

Zero-Drift, Low Power, CMOS Operational Amplifiers

1 FEATURES

- **Input Offset Voltage: 5 μ V (TYP)**
- **Input Offset Drift: \pm 0.1 μ V/ $^{\circ}$ C**
- **Low Quiescent Current: 20 μ A/Amp**
- **Gain Bandwidth: 350kHz**
- **Rail to Rail Input and Output**
- **Low Noise: 1.1 μ V_{P-P} (0.1Hz to 10Hz)**
- **Slew Rate: 0.15V/ μ s**
- **Supply Range: 1.8V to 5.5V**
- **Extended Temperature: -40 $^{\circ}$ C to +125 $^{\circ}$ C**
- **Micro SIZE PACKAGES: SOT23-5, SC70-5**

2 APPLICATIONS

- **Battery Powered Instruments**
- **Medical Instruments**
- **Handheld Test Equipment**
- **Temperature Measurements**
- **Transducers**
- **Electronic Scales**

3 DESCRIPTIONS

The RS8541A, RS8542A, RS8544A series of CMOS operational amplifiers use auto-calibration techniques to simultaneously provide very low offset voltage (5 μ V TYP) and near-zero drift over time and temperature. This family of amplifiers has ultralow noise, offset and power.

This miniature, high-precision operational amplifiers offer high input impedance and rail-to-rail input and rail-to-rail output swing. With gain-bandwidth product of 350kHz and slew rate of 0.15V/ μ s. Single or dual supplies as low as +1.8V (\pm 0.9V) and up to +5.5V (\pm 2.75V) may be used.

The RS854XA are specified for the extended industrial and automotive temperature range (-40 $^{\circ}$ C to 125 $^{\circ}$ C). The RS8541A single amplifier is available in SOT23-5 and SC70-5 packages. The RS8542A dual amplifier is available in SOP8 and MSOP8 packages. The RS8544A quad amplifier is available in SOP14 and TSSOP14 packages.

Device Information ⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE(NOM)
RS8541A	SOT23-5	2.90mm \times 1.60mm
	SC70-5	2.10mm \times 1.25mm
RS8542A	SOP8	4.90mm \times 3.90mm
	MSOP8	3.00mm \times 3.00mm
RS8544A	SOP14	8.65mm \times 3.90mm
	TSSOP14	5.00mm \times 4.40mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

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4 REVISION HISTORY

Note: Page numbers for previous revisions may differ from page numbers in the current version.

Version	Change Date	Change Item
A.0.1	2025/11/19	Preliminary version completed

Preliminary version

5 PACKAGE/ORDERING INFORMATION ⁽¹⁾

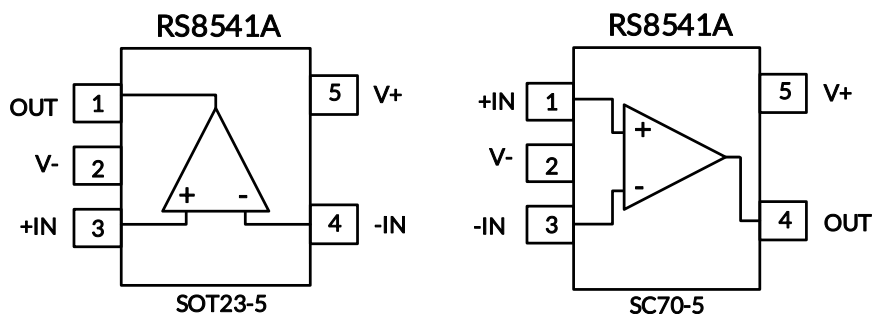
Orderable Device	Package Type	Pin	Channel	Op Temp(°C)	Device Marking ⁽²⁾	MSL ⁽³⁾	Package Qty
RS8541AXF	SOT23-5	5	1	-40°C ~125°C	8541A	MSL3	Tape and Reel, 3000
RS8541AXC5	SC70-5 ⁽⁴⁾	5	1	-40°C ~125°C	8541A	MSL3	Tape and Reel, 3000
RS8542AXK	SOP8	8	2	-40°C ~125°C	RS8542A	MSL3	Tape and Reel, 4000
RS8542AXM	MSOP8	8	2	-40°C ~125°C	RS8542A	MSL3	Tape and Reel, 4000
RS8544AXP	SOP14	14	4	-40°C ~125°C	RS8544A	MSL3	Tape and Reel, 4000
RS8544AXQ	TSSOP14	14	4	-40°C ~125°C	RS8544A	MSL3	Tape and Reel, 4000

NOTE:

- (1) This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the right-hand navigation.
- (2) There may be additional marking, which relates to the lot trace code information (data code and vendor code), the logo or the environmental category on the device.
- (3) Runic classify the MSL level with using the common preconditioning setting in our assembly factory conforming to the JEDEC industrial standard J-STD-20F. Please align with Runic if your end application is quite critical to the preconditioning setting or if you have special requirement.
- (4) Equivalent to SOT353.

Preliminary version

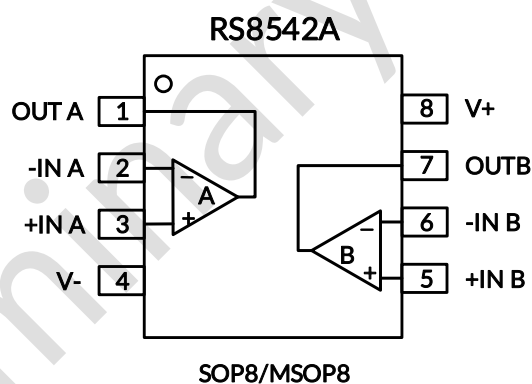
6 PIN CONFIGURATION AND FUNCTIONS



PIN DESCRIPTION

NAME	PIN		I/O ⁽¹⁾	DESCRIPTION
	SOT23-5	SC70-5		
-IN	4	3	I	Negative (inverting) input
+IN	3	1	I	Positive (noninverting) input
OUT	1	4	O	Output
V-	2	2	-	Negative (lowest) power supply
V+	5	5	-	Positive (highest) power supply

(1) I = Input, O = Output.

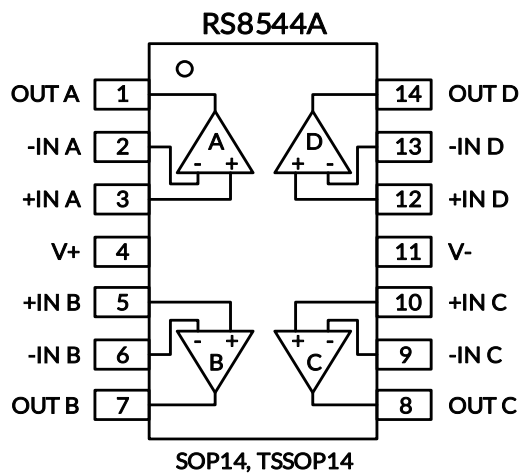


PIN DESCRIPTION

NAME	PIN		I/O ⁽¹⁾	DESCRIPTION
	SOP8/MSOP8			
-INA	2		I	Inverting input, channel A
+INA	3		I	Noninverting input, channel A
-INB	6		I	Inverting input, channel B
+INB	5		I	Noninverting input, channel B
OUTA	1		O	Output, channel A
OUTB	7		O	Output, channel B
V-	4		-	Negative (lowest) power supply
V+	8		-	Positive (highest) power supply

(1) I = Input, O = Output.

PIN CONFIGURATION AND FUNCTIONS



PIN DESCRIPTION

NAME	PIN	I/O ⁽¹⁾	DESCRIPTION
	SOP14/TSSOP14		
-INA	2	I	Inverting input, channel A
+INA	3	I	Noninverting input, channel A
-INB	6	I	Inverting input, channel B
+INB	5	I	Noninverting input, channel B
-INC	9	I	Inverting input, channel C
+INC	10	I	Noninverting input, channel C
-IND	13	I	Inverting input, channel D
+IND	12	I	Noninverting input, channel D
OUTA	1	O	Output, channel A
OUTB	7	O	Output, channel B
OUTC	8	O	Output, channel C
OUTD	14	O	Output, channel D
V-	11	-	Negative (lowest) power supply
V+	4	-	Positive (highest) power supply

(1) I=Input, O=Output.

7 SPECIFICATIONS

7.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
Voltage	Supply, $V_S=(V+) - (V-)$		7	V
	Signal input pin ⁽²⁾	(V-)-0.3	(V+) +0.3	
	Signal output pin ⁽³⁾	(V-)-0.3	(V+) +0.3	
Current	Signal input pin ⁽²⁾	-10	10	mA
	Signal output pin ⁽³⁾	-10	10	mA
	Output short-circuit ⁽⁴⁾	Continuous		
θ_{JA}	Package thermal impedance ⁽⁵⁾	SOT23-5	230	°C/W
		SC70-5	380	
		SOP8	110	
		MSOP8	170	
		SOP14	105	
		TSSOP14	90	
Temperature	Operating range, T_A	-40	125	°C
	Junction, T_J ⁽⁶⁾	-40	150	
	Storage, T_{stg}	-65	150	

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

(2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.3V beyond the supply rails should be current-limited to $\pm 10\text{mA}$ or less.

(3) Output terminals are diode-clamped to the power-supply rails. Output signals that can swing more than 0.3V beyond the supply rails should be current-limited to $\pm 10\text{mA}$ or less.

(4) Short-circuit to ground, one amplifier per package.

(5) The package thermal impedance is calculated in accordance with JESD-51.

(6) The maximum power dissipation is a function of $T_{J(\text{MAX})}$, $R_{\theta JA}$, and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(\text{MAX})} - T_A) / R_{\theta JA}$. All numbers apply for packages soldered directly onto a PCB.

7.2 ESD Ratings

The following ESD information is provided for handling of ESD-sensitive devices in an ESD protected area only.

		VALUE	UNIT
$V_{(\text{ESD})}$	Electrostatic discharge	Human-Body Model (HBM), MIL-STD-883J	± 4000
		Charged-Device Model (CDM), ANSI/ESDA/JEDEC JS-002-2025	± 1000



ESD SENSITIVITY CAUTION

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

7.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
Supply voltage, $V_S=(V+) - (V-)$	Single-supply	1.8		5.5	V
	Dual-supply	± 0.9		± 2.75	

7.4 Electrical Characteristics

Unless otherwise noted ⁽¹⁾: $T_A = +25^\circ\text{C}$, $V_S = 1.8$ to 5.5V , $R_L = 10\text{k}\Omega$, $V_{CM} = V_{OUT} = V_S/2$, Full ⁽⁹⁾ = -40°C to $+125^\circ\text{C}$.

PARAMETER	CONDITIONS	T_A	RS854XA				
			MIN ⁽²⁾	TYP ⁽³⁾	MAX ⁽²⁾	UNIT	
POWER SUPPLY							
V_S	Operating Voltage Range	FULL	1.8		5.5	V	
I_Q	Quiescent Current per Amplifier	25°C		20	28	μA	
		FULL			30		
PSRR	Power-Supply Rejection Ratio	$V_S = 1.8\text{V to } 5.5\text{V}$, $V_{CM} = 1/2V_S$	25°C	100	120	dB	
			FULL	90			
INPUT							
V_{OS}	Input Offset Voltage	$V_{CM} = V_S/2$	25°C	-15	5	15	μV
			FULL	-35		35	
$V_{OS} T_C$	Input Offset Voltage Average Drift	$V_{CM} = V_S/2$	FULL	± 0.1		$\mu\text{V}/^\circ\text{C}$	
I_B	Input Bias Current ^{(4) (5)}		25°C	-500	± 100	500	pA
I_{OS}	Input Offset Current ⁽⁴⁾		25°C		± 200		pA
A_{OL}	Open-Loop Voltage Gain	$V_{OUT} = (V_-) + 0.15\text{V to } (V_+) - 0.15\text{V}$	25°C	110	120	dB	
			FULL	100			
V_{CM}	Common-Mode Voltage Range		FULL	$(V_-) - 0.1$		$(V_+) + 0.1$	V
CMRR	Common-Mode Rejection Ratio	$V_S = 5.5\text{V}$, $V_{CM} = -0.1\text{V to } 5.6\text{V}$	25°C	110	120	dB	
			FULL	100			
OUTPUT							
V_{OH}	Output Swing from Positive Rail	$R_L = 10\text{k}\Omega$ to $V_S/2$	25°C		13	20	mV
V_{OL}	Output Swing from Negative Rail	$R_L = 10\text{k}\Omega$ to $V_S/2$	25°C		10	20	mV
I_{SC}	Output Short-Circuit Current ^{(6) (7)}	Sink, $V_S = 5\text{V}$ Source, $V_S = 5\text{V}$	25°C	8	15	mA	
				10	24		
FREQUENCY RESPONSE							
SR	Slew Rate ⁽⁸⁾	$G = 1$, $C_L = 100\text{ pF}$	25°C		0.15		$\text{V}/\mu\text{s}$
GBW	Gain-Bandwidth Product	$G = 11$, $V_{IN} = 50\text{ mV}$	25°C		350		kHz
t_s	Settling Time, 0.1%	$G = 1$, $V_{IN} = 2\text{ V Step}$	25°C		30		μs
t_{OR}	Overload Recovery Time	$V_{IN} \cdot \text{Gain} \geq V_S$, $G = 11$	25°C		18		μs
t_{ON}	Turn On Time		25°C		130		μs
PM	Phase Margin	$R_L = 10\text{K}$, $C_L = 50\text{pF}$	25°C		60		°
GM	Gain Margin	$R_L = 10\text{K}$, $C_L = 50\text{pF}$	25°C		10		dB
C_{LOAD}	Capacitive Load Drive		25°C		100		pF
NOISE							
e_{n-p-p}	Input Voltage Noise	$f = 0.1\text{ Hz to } 10\text{ Hz}$	25°C		1.1		μV_{pp}
e_n	Input Voltage Noise Density ⁽⁴⁾	$f = 1\text{ kHz}$	25°C		50		$\text{nV}/\sqrt{\text{Hz}}$

NOTE:

- (1) Electrical table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device.
- (2) Limits are 100% production tested at 25°C. Limits over the operating temperature range are ensured through correlations using statistical quality control (SQC) method.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration.
- (4) This parameter is ensured by design and/or characterization and is not tested in production.
- (5) Positive current corresponds to current flowing into the device.
- (6) The maximum power dissipation is a function of $T_{J(MAX)}$, $R_{\theta JA}$, and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} - T_A) / R_{\theta JA}$. All numbers apply for packages soldered directly onto a PCB.
- (7) Short circuit test is a momentary test.
- (8) Number specified is the slower of positive and negative slew rates.
- (9) Specified by characterization only.

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7.5 Typical Characteristics

NOTE: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only.

At $T_A = +25^\circ\text{C}$, $V_S = 5.5\text{V}$, $R_L = 10\text{k}\Omega$ connected to $V_S/2$, $V_{OUT} = V_S/2$, unless otherwise noted.

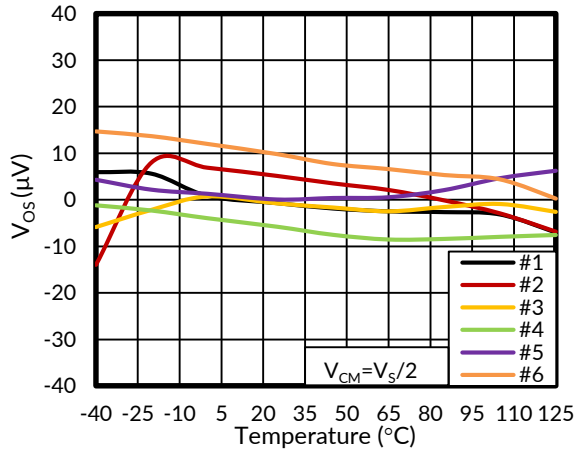


Figure 1. Offset Voltage vs Temperature

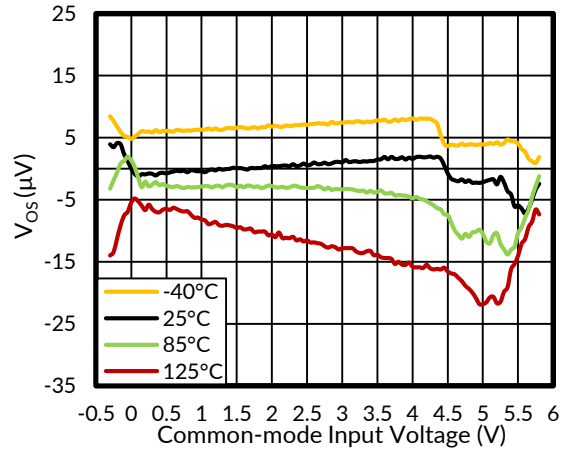


Figure 2. Input Offset Voltage vs Common-mode Input Voltage

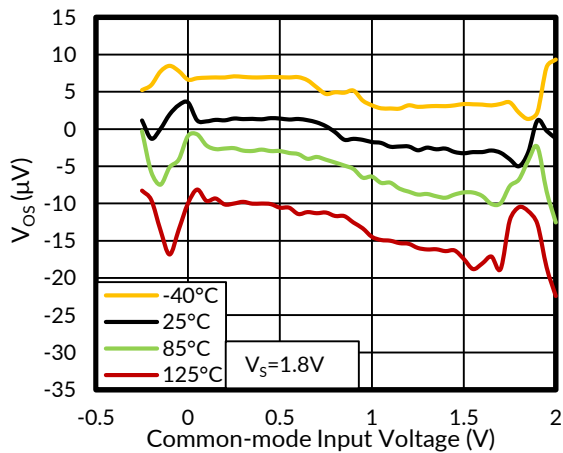


Figure 3. Input Offset Voltage vs Common-mode Input Voltage

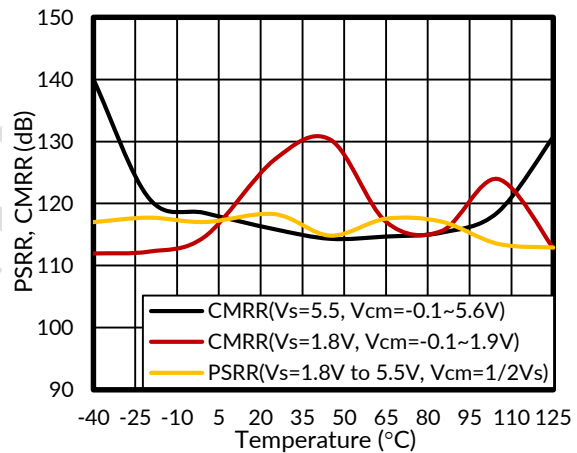


Figure 4. Common-mode Rejection Ratio, Power Supply Rejection Ratio vs Ambient Temperature

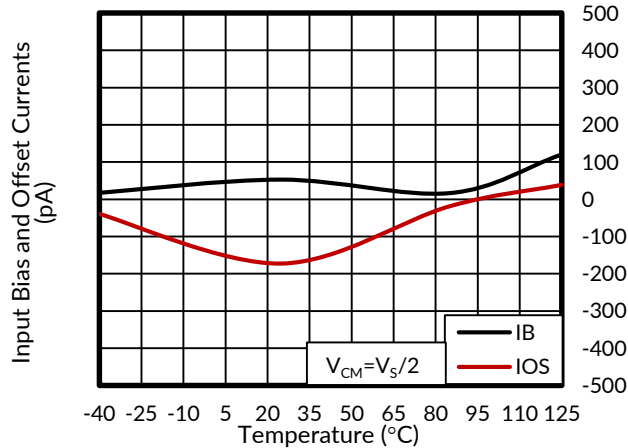


Figure 5. Input Bias, Offset Currents vs Ambient Temperature

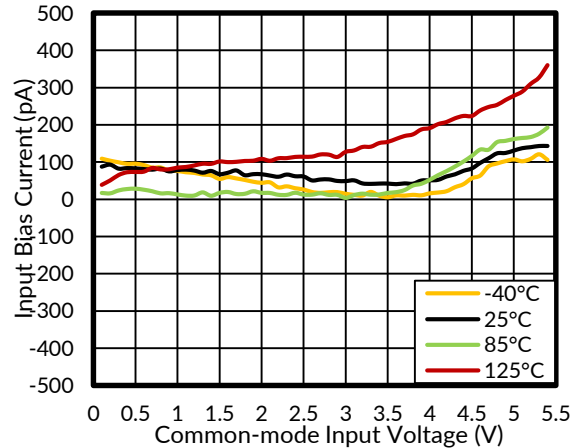


Figure 6. Input Bias Current vs Common-mode Input Voltage

Typical Characteristics

NOTE: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only.

At $T_A = +25^\circ\text{C}$, $V_S = 5.5\text{V}$, $R_L = 10\text{k}\Omega$ connected to $V_S/2$, $V_{OUT} = V_S/2$, unless otherwise noted.

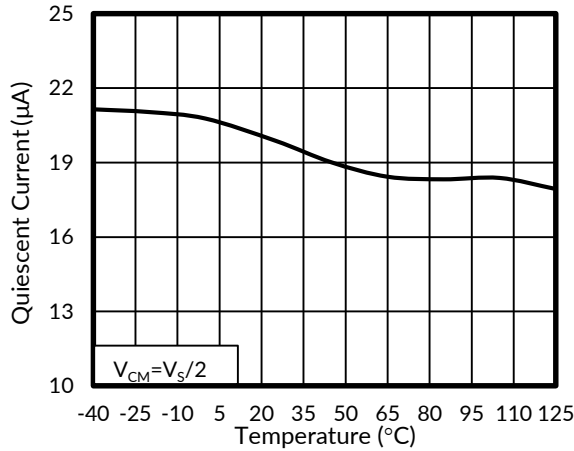


Figure 7. Quiescent Current vs Ambient Temperature

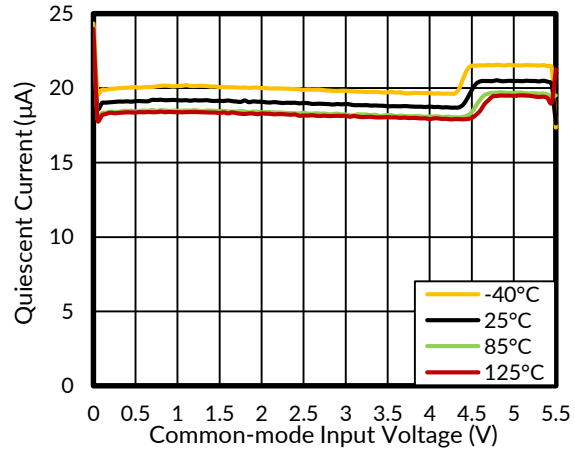


Figure 8. Quiescent Current vs Common-mode Input Voltage

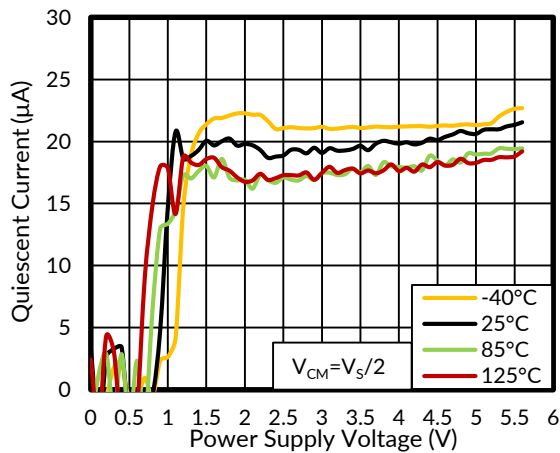


Figure 9. Quiescent Current vs Power Supply Voltage

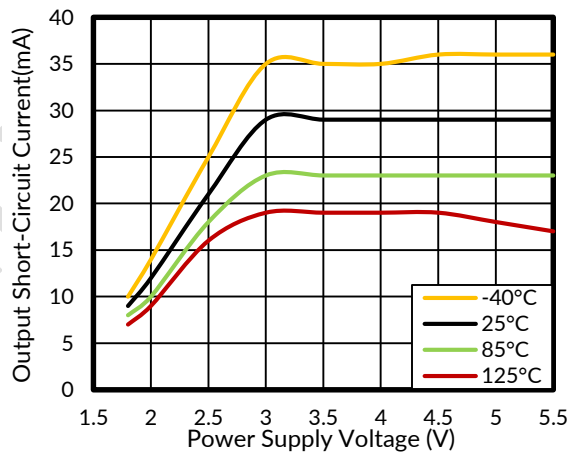


Figure 10. Output Short-Circuit Current (Sink) vs Power Supply Voltage

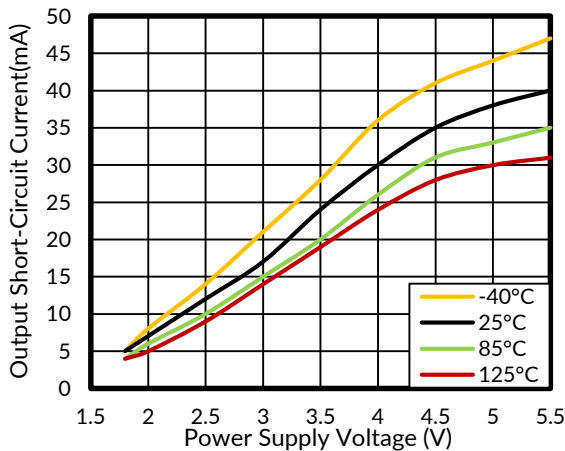


Figure 11. Output Short-Circuit Current (Source) vs Power Supply Voltage

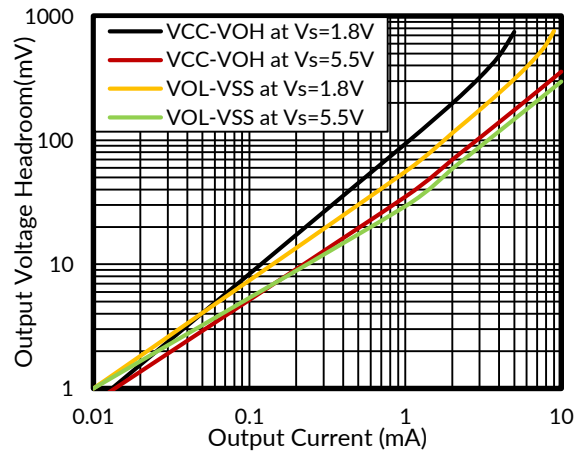


Figure 12. Output Voltage Headroom vs Output Current

Typical Characteristics

NOTE: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only.

At $T_A = +25^\circ\text{C}$, $V_S = 5.5\text{V}$, $R_L = 10\text{k}\Omega$ connected to $V_S/2$, $V_{OUT} = V_S/2$, unless otherwise noted.

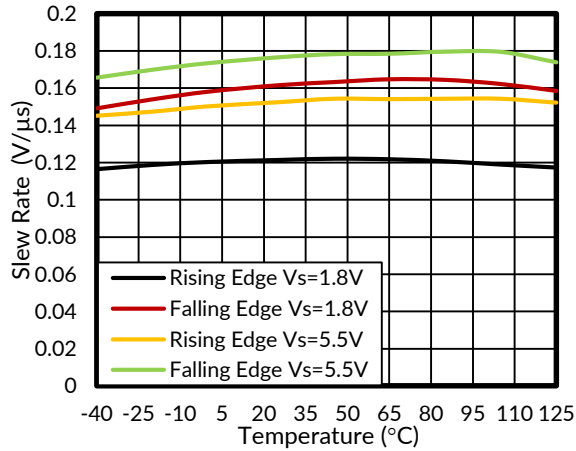


Figure 13. Slew Rate vs Ambient Temperature

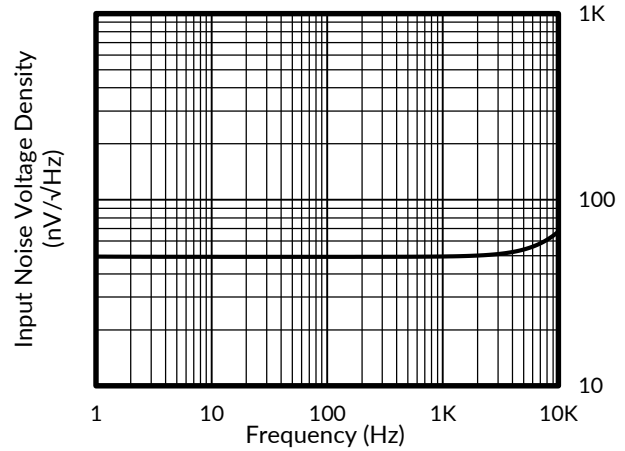


Figure 14. Input Noise Voltage Density vs Frequency

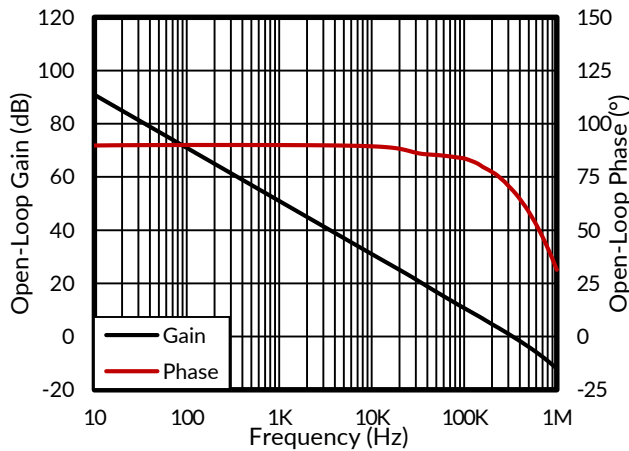


Figure 15. Open-Loop Gain, Phase vs Frequency

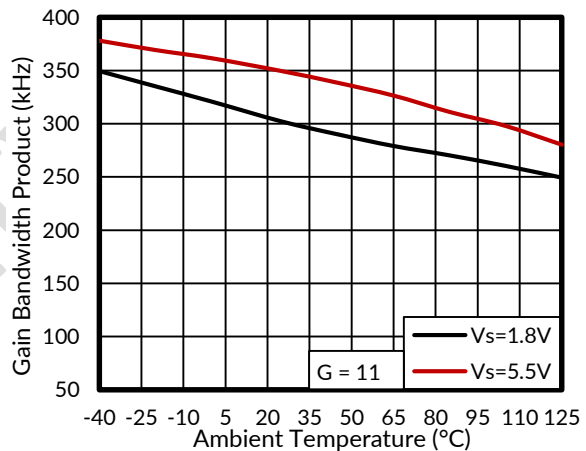


Figure 16. Gain Bandwidth Product vs Ambient Temperature

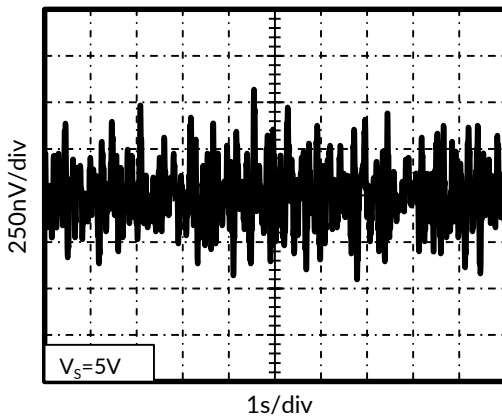


Figure 17. 0.1Hz~10Hz Noise

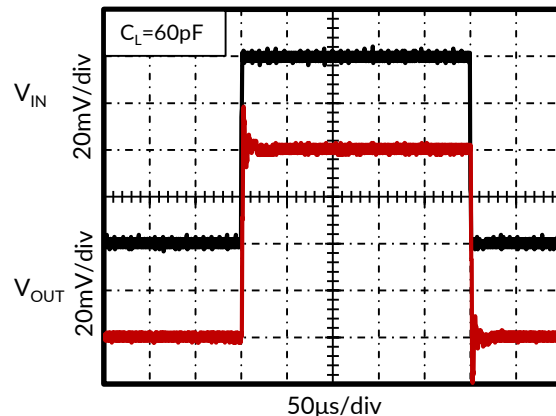


Figure 18. Small-Signal Noninverting Pulse Response

Typical Characteristics

NOTE: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only.

At $T_A = +25^\circ\text{C}$, $V_S = 5.5\text{V}$, $R_L = 10\text{k}\Omega$ connected to $V_S/2$, $V_{OUT} = V_S/2$, unless otherwise noted.

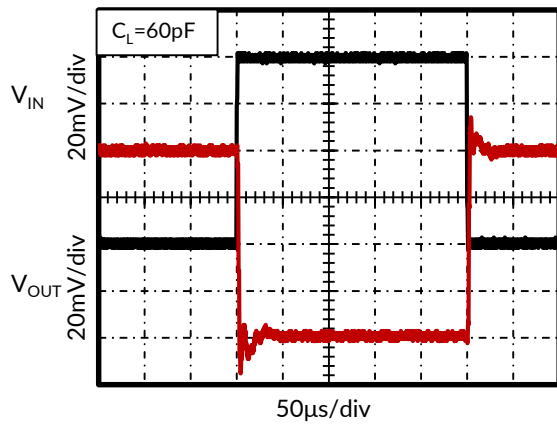


Figure 19. Small-Signal Inverting Pulse Response

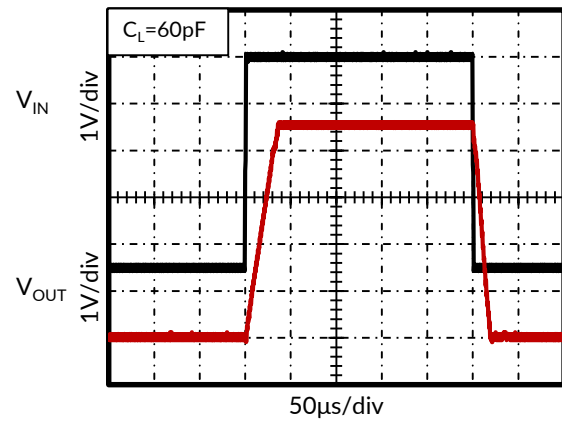


Figure 20. Large-Signal Noninverting Pulse Response

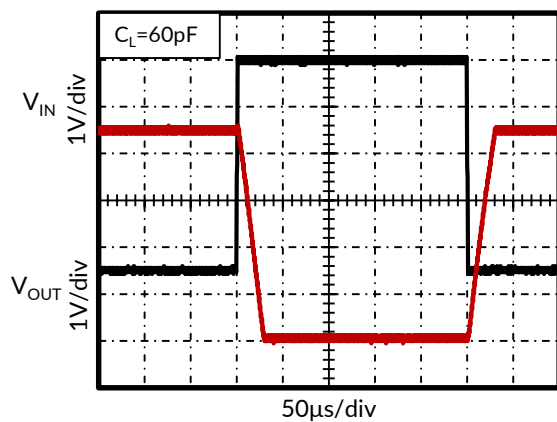


Figure 21. Large-Signal Inverting Pulse Response

8 DETAILED DESCRIPTION

8.1 Overview

The RS854XA is a family of Zero-Drift, low-power, rail-to-rail input and output operational amplifiers. These devices operate from 1.8 V to 5.5 V, are unity-gain stable, and are suitable for a wide range of general-purpose applications. The Zero-Drift architecture provides ultra low offset voltage and near-zero offset voltage drift.

8.2 Feature Description

The RS854XA series op amps are unity-gain stable and free from unexpected output phase reversal. They use auto-zeroing techniques to provide low offset voltage and very low drift over time and temperature.

Good layout practice mandates use of a 0.1 μ F capacitor placed closely across the supply pins.

For lowest offset voltage and precision performance, circuit layout and mechanical conditions should be optimized. Avoid temperature gradients that create thermoelectric (Seebeck) effects in thermocouple junctions formed from connecting dissimilar conductors. These thermally-generated potentials can be made to cancel by assuring that they are equal on both input terminals.

- Use low thermoelectric-coefficient connections (avoid dissimilar metals).
- Thermally isolate components from power supplies or other heat-sources.
- Shield op amp and input circuitry from air currents, such as cooling fans.

Following these guidelines will reduce the likelihood of junctions being at different temperatures, which can cause thermoelectric voltages of 0.1 μ V/ $^{\circ}$ C or higher, depending on materials used.

8.3 Operating Voltage

The RS854XA series op amps operate over a power-supply range of +1.8V to +5.5V (\pm 0.9V to \pm 2.75V). Supply voltages higher than 7V (absolute maximum) can permanently damage the amplifier. Parameters that vary over supply voltage or temperature are shown in the Typical Characteristics section of this data sheet.

8.4 Device Functional Modes

The RS854XA device has a single functional mode. The device is powered on as long as the power supply voltage is between 1.8 V (\pm 0.9 V) and 5.5 V (\pm 2.75 V).

9 APPLICATION AND IMPLEMENTATION

Information in the following applications sections is not part of the Runic component specification, and Runic does not warrant its accuracy or completeness. Runic's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Note

The RS854XA is a unity-gain stable, precision operational amplifier with very low offset voltage drift; these devices are also free from output phase reversal. Applications with noisy or high-impedance power supplies require decoupling capacitors close to the device power-supply pins. In most cases, 0.1 μ F capacitors are adequate.

9.2 Typical Applications

9.2.1 Bidirectional Current-Sensing

This single-supply, low-side, bidirectional current-sensing solution detects load currents from -1 A to 1 A. The single-ended output spans from 110 mV to 3.19 V. This design uses the RS854XA because of its low offset voltage and rail-to-rail input and output. One of the amplifiers is configured as a difference amplifier and the other provides the reference voltage.

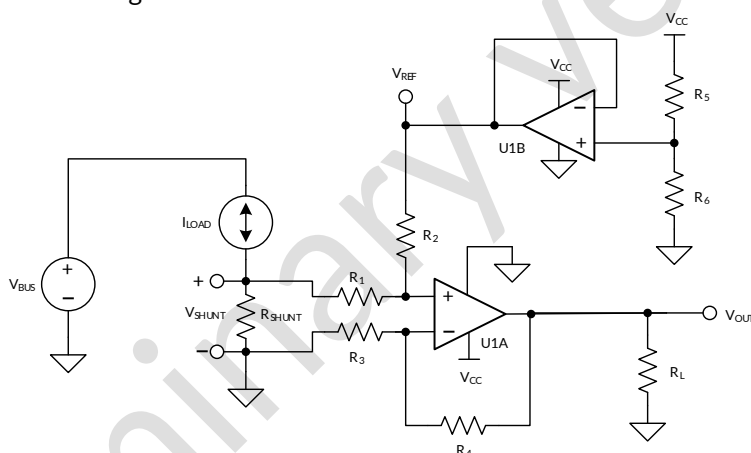


Figure 22. Bidirectional Current-Sensing Schematic

9.2.2 Design Requirements

This solution has the following requirements:

- Supply voltage: 3.3 V
- Input: -1 A to 1 A
- Output: 1.65 V \pm 1.54 V (110 mV to 3.19 V)

9.2.3 Detailed Design Procedure

The load current, I_{LOAD} , flows through the shunt resistor (R_{SHUNT}) to develop the shunt voltage, V_{SHUNT} . The shunt voltage is then amplified by the difference amplifier, which consists of U1A and R_1 through R_4 . The gain of the difference amplifier is set by the ratio of R_4 to R_3 . To minimize errors, set $R_2 = R_4$ and $R_1 = R_3$. The reference voltage, V_{REF} , is supplied by buffering a resistor divider using U1B. The transfer function is given by Equation 1.

$$V_{OUT} = V_{SHUNT} \times \text{Gain}_{\text{Diff_Amp}} + V_{REF}$$

Where

$$V_{SHUNT} = I_{LOAD} \times R_{SHUNT}$$

$$\text{Gain}_{\text{Diff_Amp}} = \frac{R_4}{R_3}$$

$$V_{REF} = V_{CC} \times \left[\frac{R_6}{R_5 + R_6} \right] \quad (1)$$

There are two types of errors in this design: offset and gain. Gain errors are introduced by the tolerance of the shunt resistor and the ratios of R_4 to R_3 and, similarly, R_2 to R_1 . Offset errors are introduced by the voltage divider (R_5 and R_6) and how closely the ratio of R_4/R_3 matches R_2/R_1 . The latter value impacts the CMRR of the difference amplifier, which ultimately translates to an offset error. Because this is a low-side measurement, the value of V_{SHUNT} is the ground potential for the system load. Therefore, it is important to place a maximum value on V_{SHUNT} . In this design, the maximum value for V_{SHUNT} is set to 100 mV. Equation 2 calculates the maximum value of the shunt resistor given a maximum shunt voltage of 100 mV and maximum load current of 1 A.

$$R_{SHUNT(Max)} = \frac{V_{SHUNT(Max)}}{I_{LOAD(Max)}} = \frac{100 \text{ mV}}{1 \text{ A}} = 100 \text{ m}\Omega \quad (2)$$

The tolerance of R_{SHUNT} is directly proportional to cost. For this design, a shunt resistor with a tolerance of 0.5% was selected. If greater accuracy is required, select a 0.1% resistor or better.

The load current is bidirectional; therefore, the shunt voltage range is -100 mV to 100 mV. This voltage is divided down by R_1 and R_2 before reaching the operational amplifier, U1A. Take care to ensure that the voltage present at the noninverting node of U1A is within the common-mode range of the device. Therefore, it is important to use an operational amplifier, such as the RS854XA, that has a common-mode range that extends below the negative supply voltage. Finally, to minimize offset error, note that the RS854XA has a typical offset voltage of $\pm 5\mu\text{V}$ ($\pm 15\mu\text{V}$ maximum). Given a symmetric load current of -1 A to 1 A, the voltage divider resistors (R_5 and R_6) must be equal. To be consistent with the shunt resistor, a tolerance of 0.5% was selected. To minimize power consumption, 10-k Ω resistors were used. To set the gain of the difference amplifier, the common-mode range and output swing of the RS854XA must be considered. Equation 3 and Equation 4 depict the typical common-mode range and maximum output swing, respectively, of the RS854XA given a 3.3-V supply.

$$-100\text{mV} < V_{CM} < 3.4\text{V} \quad (3)$$

$$100\text{mV} < V_{OUT} < 3.2\text{V} \quad (4)$$

The gain of the difference amplifier can now be calculated as shown in Equation 5.

$$\text{Gain}_{\text{Diff_Amp}} = \frac{V_{OUT_Max} - V_{OUT_Min}}{R_{SHUNT} \times (I_{MAX} - I_{MIN})} = \frac{3.2 \text{ V} - 100 \text{ mV}}{100 \text{ m}\Omega \times [1 \text{ A} - (-1 \text{ A})]} = 15.5 \frac{\text{V}}{\text{V}} \quad (5)$$

The resistor value selected for R_1 and R_3 was 1k Ω . 15.4k Ω was selected for R_2 and R_4 because it is the nearest standard value. Therefore, the ideal gain of the difference amplifier is 15.4 V/V.

The gain error of the circuit primarily depends on R_1 through R_4 . As a result of this dependence, 0.1% resistors were selected. This configuration reduces the likelihood that the design requires a two-point calibration. A simple one-point calibration, if desired, removes the offset errors introduced by the 0.5% resistors.

9.2.4 Application Curve

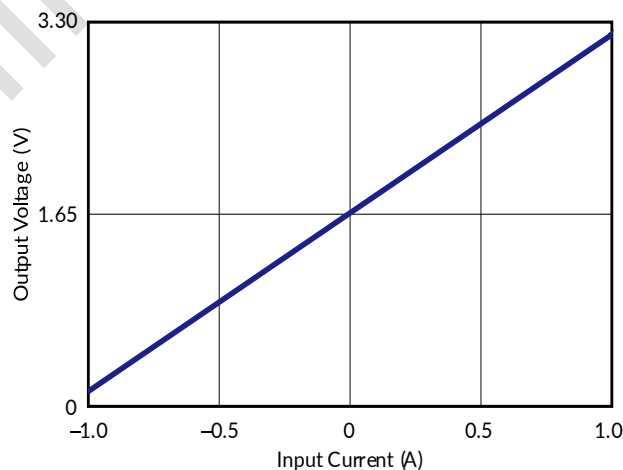


Figure 23. Bidirectional Current-Sensing Circuit Performance: Output Voltage vs Input Current

10 LAYOUT

10.1 Layout Guidelines

Attention to good layout practices is always recommended. Keep traces short. When possible, use a PCB ground plane with surface-mount components placed as close to the device pins as possible. Place a $0.1\mu\text{F}$ capacitor closely across the supply pins.

These guidelines should be applied throughout the analog circuit to improve performance and provide benefits such as reducing the EMI susceptibility.

10.2 Layout Example

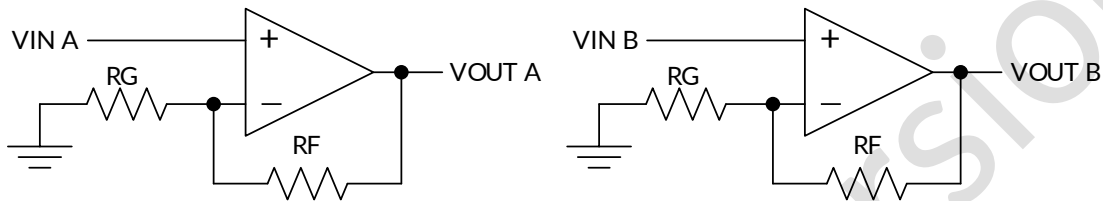


Figure 24. Schematic Representation

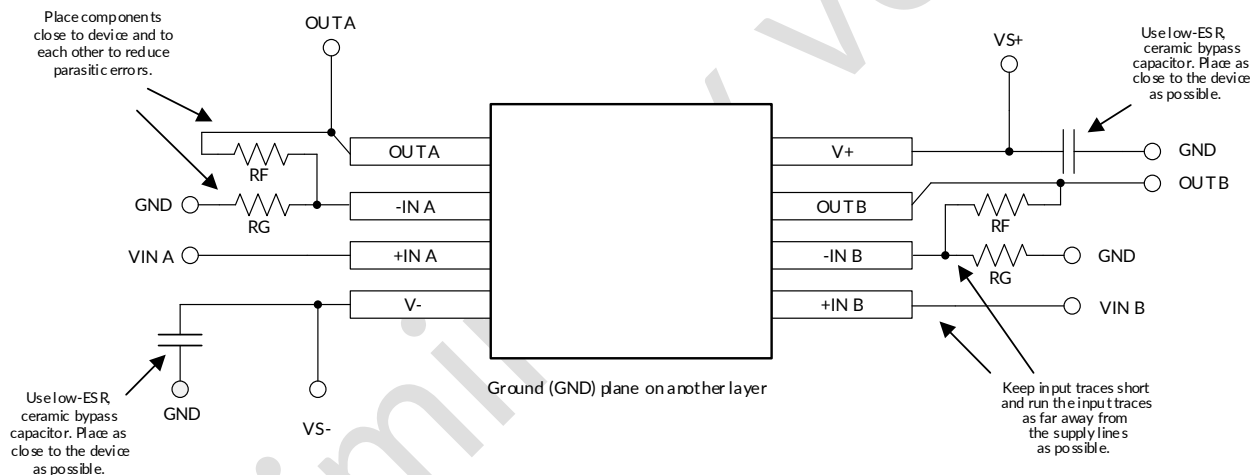
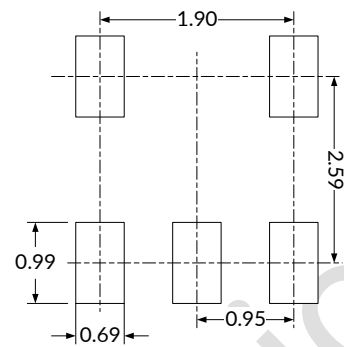
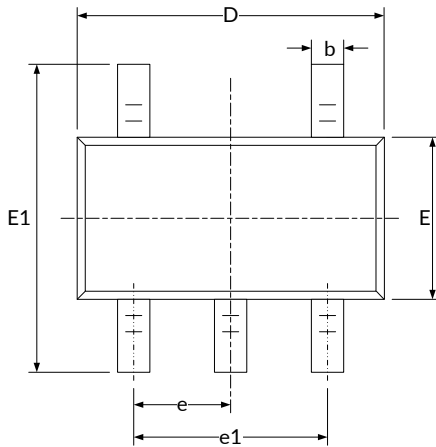
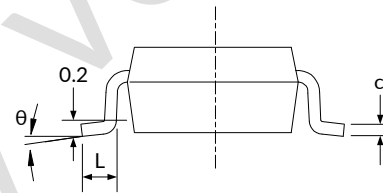
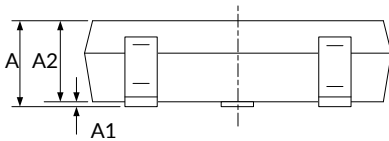


Figure 25. Layout Example

NOTE: Layout Recommendations have been shown for dual op-amp only, follow similar precautions for Single and four.

11 PACKAGE OUTLINE DIMENSIONS

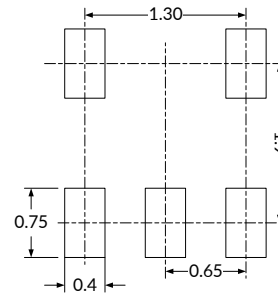
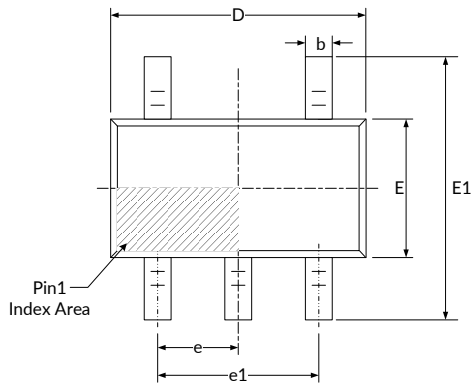
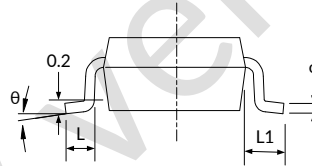
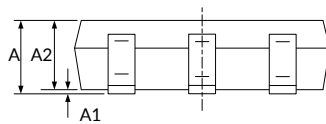
SOT23-5⁽³⁾


RECOMMENDED LAND PATTERN (Unit: mm)


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A ⁽¹⁾	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D ⁽¹⁾	2.820	3.020	0.111	0.119
E ⁽¹⁾	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC) ⁽²⁾		0.037(BSC) ⁽²⁾	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

NOTE:

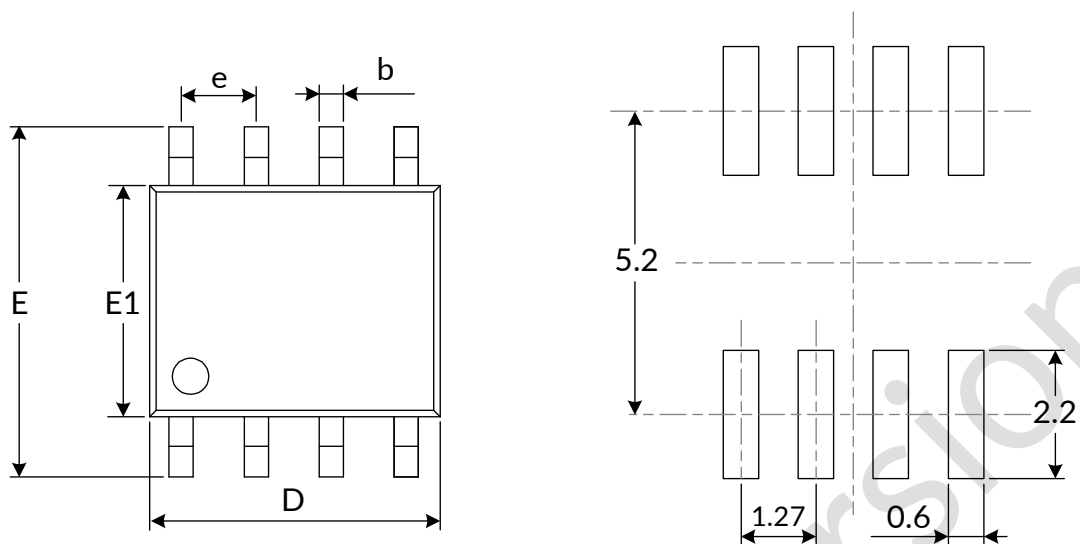
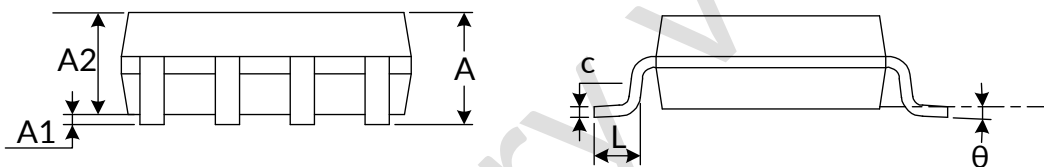
1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
2. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
3. This drawing is subject to change without notice.

SC70-5 (3)

RECOMMENDED LAND PATTERN (Unit: mm)


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A ⁽¹⁾	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
c	0.080	0.150	0.003	0.006
D ⁽¹⁾	2.000	2.200	0.079	0.087
E ⁽¹⁾	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650(BSC) ⁽²⁾		0.026(BSC) ⁽²⁾	
e1	1.300(BSC) ⁽²⁾		0.051(BSC) ⁽²⁾	
L	0.260	0.460	0.010	0.018
L1	0.525		0.021	
θ	0°	8°	0°	8°

NOTE:

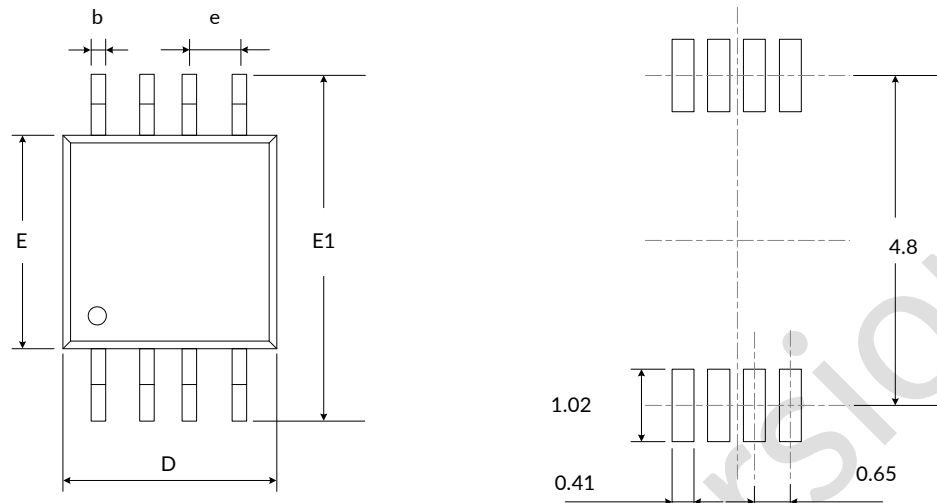
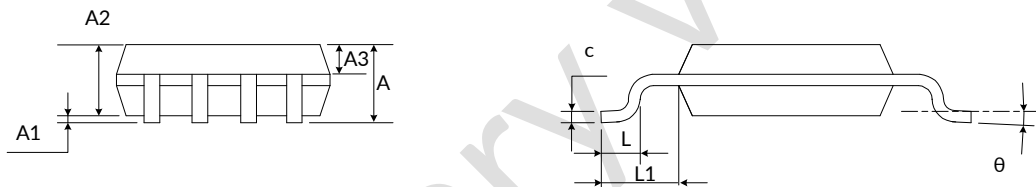
1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
2. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
3. This drawing is subject to change without notice.

SOP8⁽³⁾

RECOMMENDED LAND PATTERN (Unit: mm)


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A ⁽¹⁾	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D ⁽¹⁾	4.800	5.000	0.189	0.197
e	1.270(BSC) ⁽²⁾		0.050(BSC) ⁽²⁾	
E	5.800	6.200	0.228	0.244
E1 ⁽¹⁾	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

NOTE:

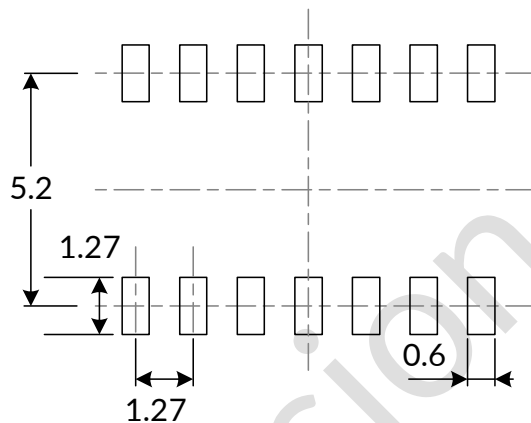
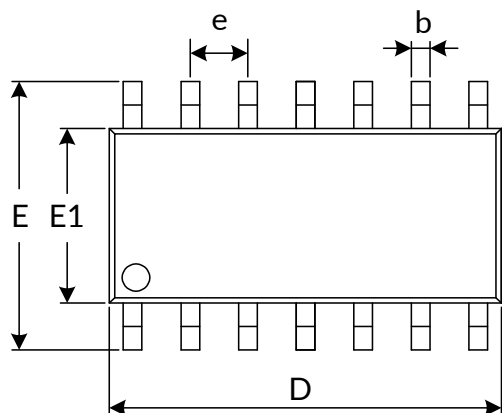
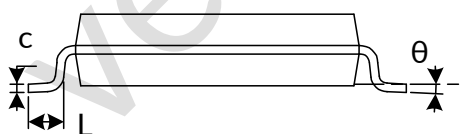
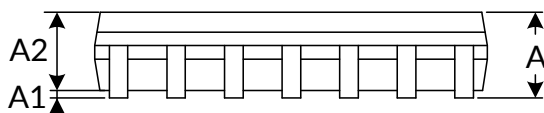
1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
2. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
3. This drawing is subject to change without notice.

MSOP8⁽⁴⁾

RECOMMENDED LAND PATTERN (Unit: mm)


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A ⁽¹⁾		1.100		0.043
A1	0.050	0.150	0.002	0.006
A2	0.750	0.950	0.030	0.037
A3	0.300	0.400	0.012	0.016
b	0.280	0.360	0.011	0.014
c	0.150	0.190	0.006	0.007
D ⁽¹⁾	2.900	3.100	0.114	0.122
e	0.650(BSC) ⁽²⁾		0.026(BSC) ⁽²⁾	
E ⁽¹⁾	2.900	3.100	0.114	0.122
E1	4.700	5.100	0.185	0.200
L	0.400	0.700	0.016	0.027
L1	0.950(REF) ⁽³⁾		0.037(REF) ⁽³⁾	
θ	0°	8°	0°	8°

NOTE:

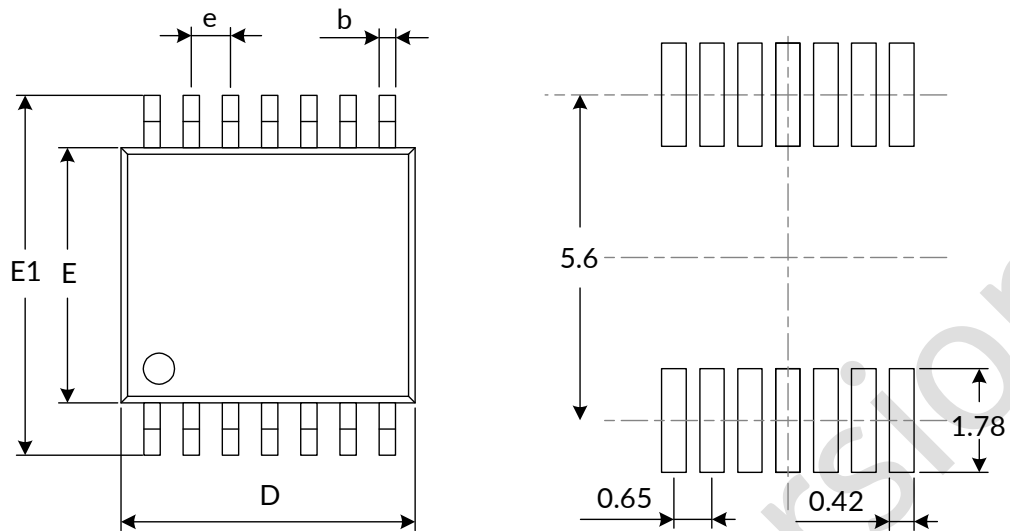
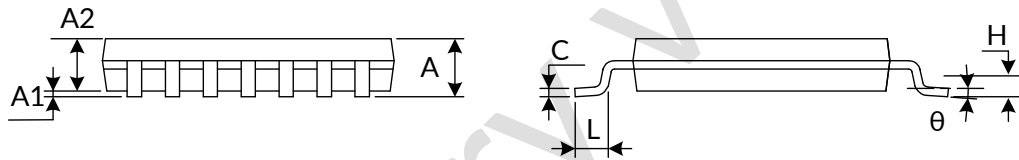
1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
2. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
3. REF is the abbreviation for Reference.
4. This drawing is subject to change without notice.

SOP14⁽³⁾

RECOMMENDED LAND PATTERN (Unit: mm)


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A ⁽¹⁾	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.310	0.510	0.012	0.020
c	0.100	0.250	0.004	0.010
D ⁽¹⁾	8.450	8.850	0.333	0.348
e	1.270(BSC) ⁽²⁾		0.050(BSC) ⁽²⁾	
E	5.800	6.200	0.228	0.244
E1 ⁽¹⁾	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

NOTE:

1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
2. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
3. This drawing is subject to change without notice.

TSSOP14⁽³⁾

RECOMMENDED LAND PATTERN (Unit: mm)


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A ⁽¹⁾		1.200		0.047
A1	0.050	0.150	0.002	0.006
A2	0.800	1.050	0.031	0.041
b	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
D ⁽¹⁾	4.860	5.100	0.191	0.201
E ⁽¹⁾	4.300	4.500	0.169	0.177
E1	6.250	6.550	0.246	0.258
e	0.650(BSC) ⁽²⁾		0.026(BSC) ⁽²⁾	
L	0.500	0.700	0.020	0.028
H	0.250(TYP)		0.010(TYP)	
θ	1°	7°	1°	7°

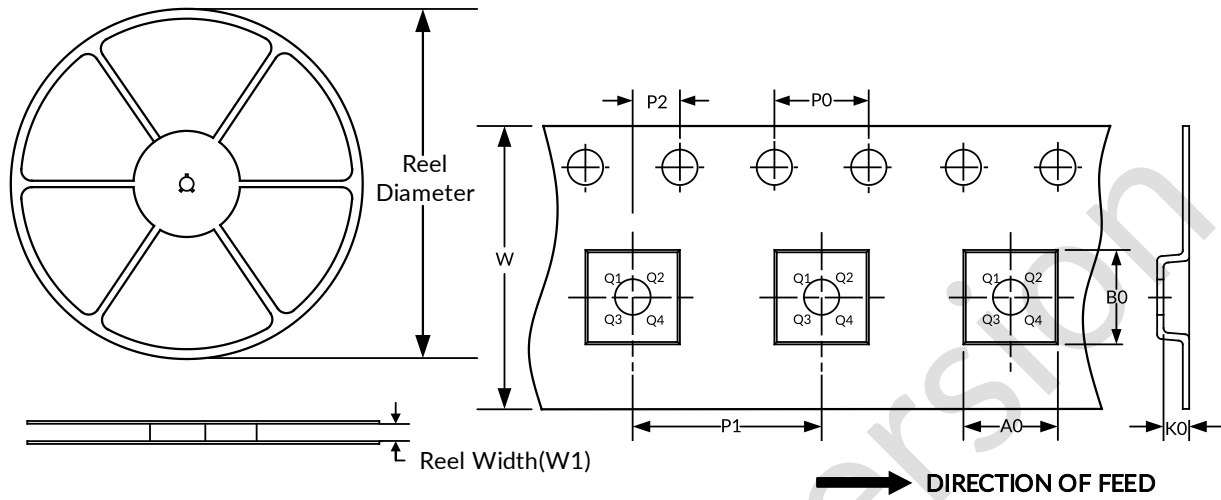
NOTE:

1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
2. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
3. This drawing is subject to change without notice.

12 TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSION



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOT23-5	7"	9.5	3.20	3.20	1.40	4.0	4.0	2.0	8.0	Q3
SC70-5	7"	9.5	2.25	2.55	1.20	4.0	4.0	2.0	8.0	Q3
SOP8	13"	12.4	6.40	5.40	2.10	4.0	8.0	2.0	12.0	Q1
MSOP8	13"	12.4	5.20	3.30	1.50	4.0	8.0	2.0	12.0	Q1
SOP14	13"	16.4	6.60	9.30	2.10	4.0	8.0	2.0	16.0	Q1
TSSOP14	13"	12.4	6.95	5.60	1.20	4.0	8.0	2.0	12.0	Q1

NOTE:

1. All dimensions are nominal.
2. Plastic or metal protrusions of 0.15mm maximum per side are not included.

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Preliminary version